

### **3W Power Amplifier Module** 4.0-5.9 GHz

Rev. V2 Mimix Broadband

#### **Features**

- 34 dBm P1dB
- Pout 26 dBm @ EVM = 2.5% (PAR=9.17 dB)
- 46 dBm OIP3
- 18.5 dB Gain
- 8V Voltage Supply
- Input Internally Matched
- 7x7mm Surface Mount Package
- Ideal for WiMAX Applications @ 5.8 GHz and
- Applications between 4 GHz and 5 GHz
- RoHS\* Compliant and 260°C Reflow Compatible

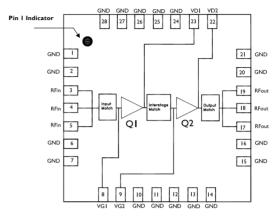
#### **Description**

The XP1044 is a highly linear 2-stage power amplifier capable of 18.5 dB of gain, 34 dBm of power at 1 dB compression and is housed in an RoHS compliant 7x7mm package. The XP1044 provides less than 2.5% EVM at 26 dBm output power with 802.16 OFDM signal and peak to average ratio 9.17 dB. The input and output of the device are internally pre-matched facilitating a simplified input and output match. This product operates off an 8V voltage supply and requires negative voltage which is used for current control. The XP1044-QL is specifically designed for WiMAX applications between 4.9 GHz and 5.9 GHz, and the performance can be shifted by adding external matching components to cover applications between 4.0 GHz and 5.0 GHz.

#### **Ordering Information**

Part Number	Package		
XP1044-QL-0N00	bulk quantity		
XP1044-QL-EV1	evaluation module for 4.9 GHz ~ 5.9 GHz		
XP1044-QL-EV2	evaluation module for 4.0 GHz ~ 5.0 GHz		

#### **Functional Block Diagram**



#### **Pin Configuration**

Pin No.	Function	Pin No.	Function
3,4,5	RF IN	23	VD1
8	VG!	22	VD2
9	VG2	1,2,6,7,10, 11,12,13, 14,15,16, 20,21,24, 25,26,27, 28	GND
17,18,19	RF OUT		

### **Absolute Maximum Ratings**

Parameter	Absolute Max.		
Drain Supply Voltage (Vd)	+9.0 V		
Gate Supply Voltage (Vg)	0 V ~ -5 V		
RF Input Power (RFin)	+23 dBm		
Stage 1 Current (Idd1)	375 mA		
Stage 2 Current (Idd2)	750 mA		
Power Dissipation (PDC)	9,0 W		
Storage Temperature	-55 °C to +150 °C		
Junctions Temperature	175 °C		
Operating Temperature (Ta)	-40 °C to See Note 2		
ESD (HBM)	Class 1A		
Moisture Sensitivity level	MSL3		
Thermal Resistance (Rth) <sup>1</sup>	15.6 °C		

<sup>\*</sup>Thermal resistance of stage 2 only

Calculate maximum operating backside temperature using: Tmax = 167 °C - [Vd\*Idd2\*Rth]. Thermal resistance of the 1st stage is 2x Rth of the output stage, and therefore Idd1 must not exceed ½ Idd2 for a specific maximum temperature



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### Electrical Specifications: 4.9-5.9 GHz (5.8 GHz Typ.) (Ambient Temperature T = 25°C)<sup>1</sup>

Parameter	Units	Min.	Тур.	Max.
Power Gain	dB	16.5	18.5	
Linear Power (@ EVM=2.5%, OFDM, 802.16 PAR=9.17 dB)	dBm		26.0	
Input Return Loss (S11)	dB		-10.0	
Output IP3 @ 22 dBm/Tone	dBm	44	46.0	
Noise Figure	dB		5	
Output P1dB	dBm	32.5	34.0	
Stage 1 Supply Current (Idd1)	mA		300	
Stage 2 Supply Current (Idd2)	mA		600	
Stage 1 Gate Voltage (Vg1)	V	-1.2	-0.85	-0.5
Stage 2 Gate Voltage (Vg2)	V	-1.2	-0.85	-0.5
Supply Voltage (Vd1 & Vd2)	V		8.0	

Unless otherwise specified, the following specifications are guaranteed at room temperature in a M/A-COM Tech test fixture.

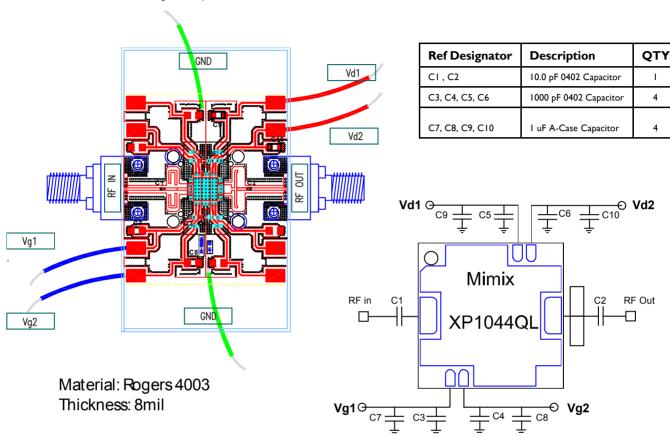
typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.



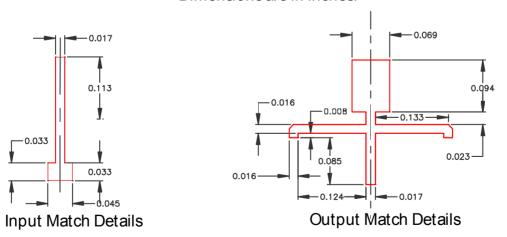
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### Evaluation Board Layout (4.9 GHz ~ 5.9 GHz



#### Dimensions are in inches.



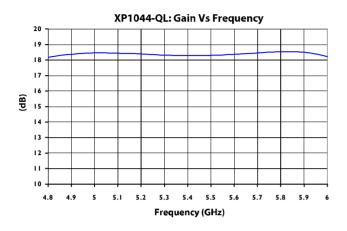
For improved performance at 6 GHz the thick transmission line (W=0.069") on the output can be extended to touch the two open stubs.

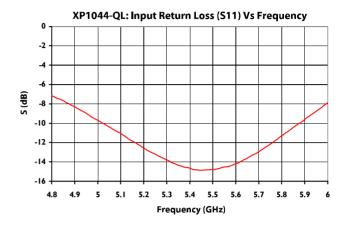


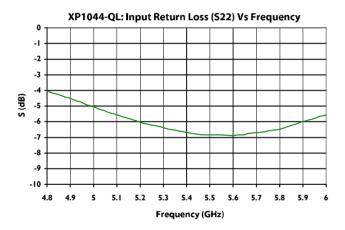
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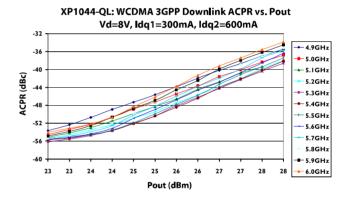
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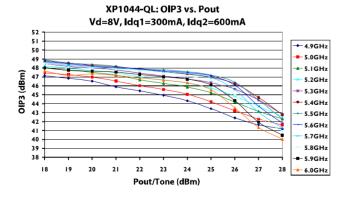
### Typical Performance Curves (EV1, Idq1 = 300 mA, Idq2 = 600 mA)

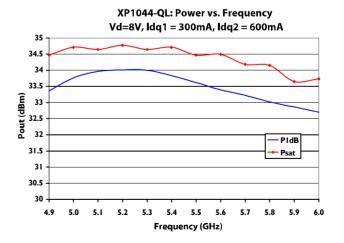












Commitment to produce in volume is not guaranteed.

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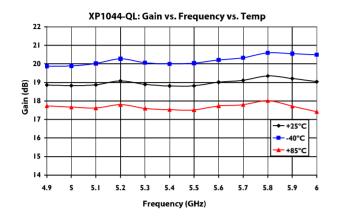
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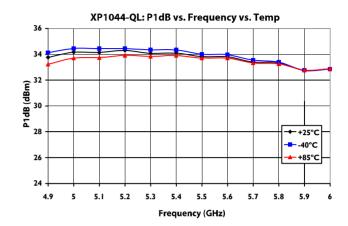


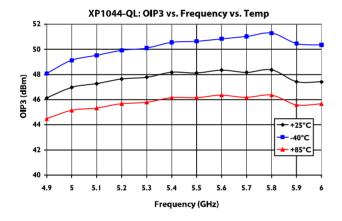
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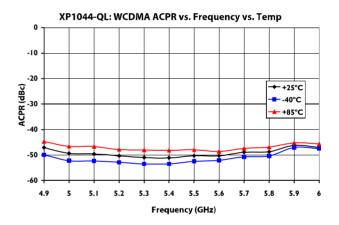
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### Typical Performance Curves (EV1, Idq1 = 300 mA, Idq2 = 600 mA, Over Temp)







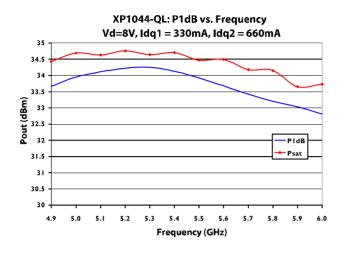


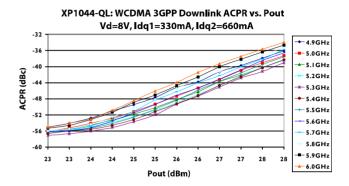


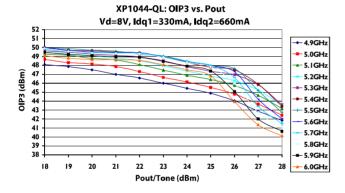
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### Typical Performance Curves (EV1, Idq1 = 330 mA, Idq2 = 660 mA)







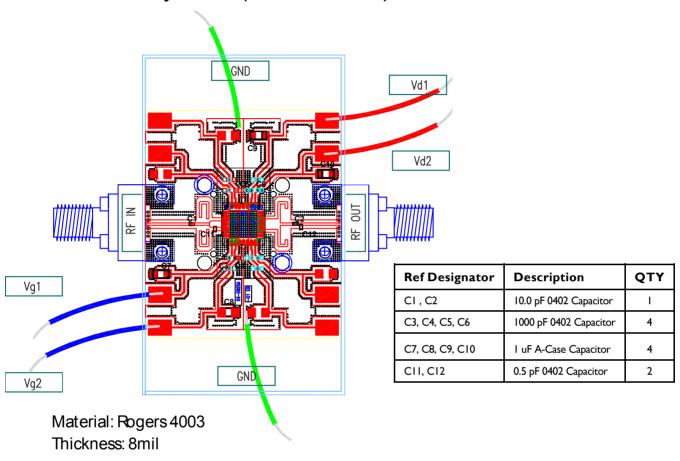
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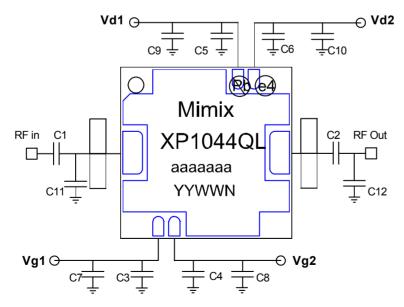


# 3W Power Amplifier Module 4.0-5.9 GHz

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### Evaluation Board Layout: EV2 (4.0 GHz ~ 5.0 GHz)





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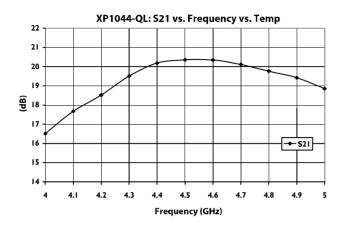
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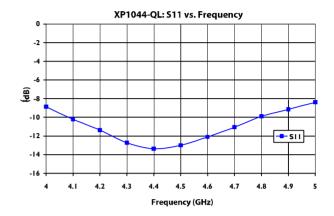


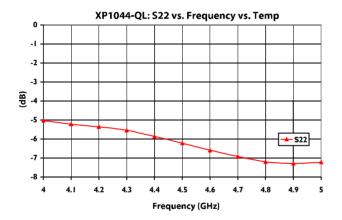
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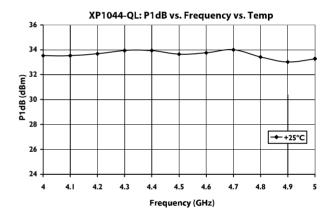
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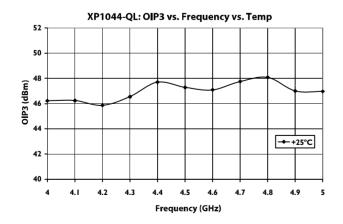
## Typical Performance Curves (EV2, Idq1 = 300 mA, Idq2 = 600 mA)

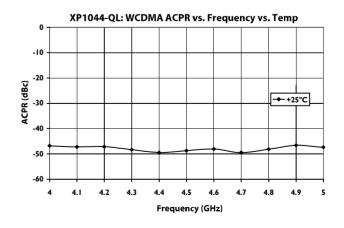












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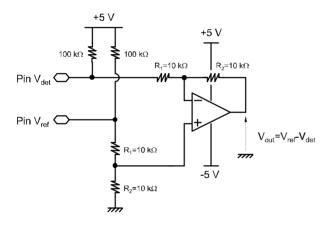
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**App Note [1] Biasing -** The XP1044-QL requires power supply sequencing. Negative voltage supply (VG) needs to be turned on first and then positive voltage can be applied to the drain (VD). When turning off the device, the positive supply (VD) should be turned off first and then negative voltage (VG) can be removed.

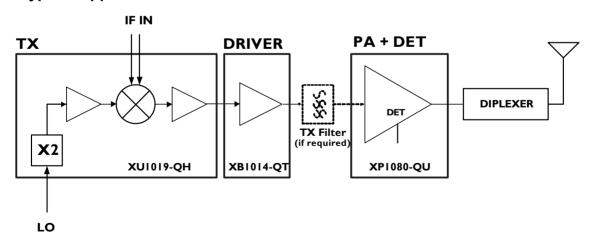
The gate voltage is adjusted in order to set the drain current to the desired level. The gate voltage required to achieve a certain current can vary over temperature and from one device to another due to pinch-off voltage variation. Constant drain current can be achieved by implementing an active bias circuit which allows for temperature compensation and eliminates the effect of pinch off voltage variation.

The input stage transistor periphery is half of the output stage transistor periphery and therefore the gate voltages needed to set the first stage current to 300mA and the second stage current to 600mA are the same. The gate voltages can be connected together and a single active bias circuit can be implemented adding a total of 6 components at a cost of approximately \$0.15.



#### **Typical Application**

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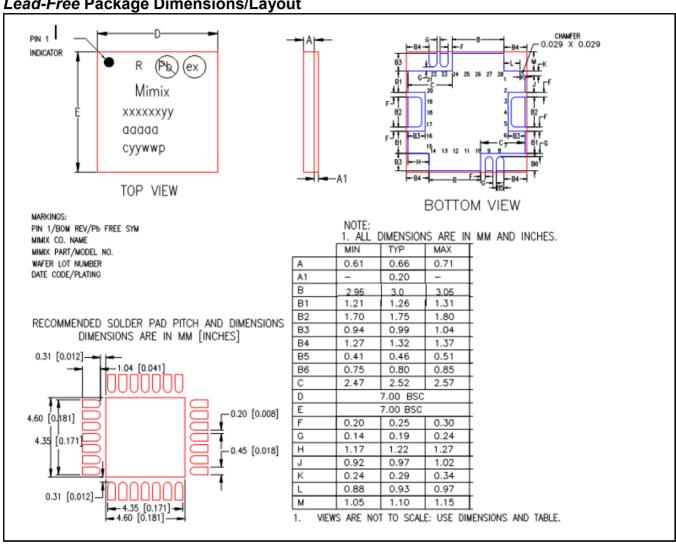
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#### Lead-Free Package Dimensions/Layout



#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these class 2 devices.

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